

IGBT MODULE (L series)

■ Features

- High Speed Switching
- Low Saturation Voltage
- Voltage Drive

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial Machines, such as Welding Machines

■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V_{CES}	1200	V
Gate-Emitter Voltage	V_{GES}	± 20	V
Collector Current	Continuous	I_C	200
	1ms	$I_{C\ pulse}$	400
	Continuous	$-I_C$	200
	1ms	$-I_{C\ pulse}$	400
Max. Power Dissipation	P_C	1600	W
Operating Temperature	T_j	+150	°C
Storage Temperature	T_{stg}	-40 to +125	°C
Net. Weight		415	g
Isolation Voltage	AC, 1min.	V_{isol}	2500
Screw Torque	Mounting *1	35	kg•cm
	Terminals *2	45	
	Terminals *3	17	

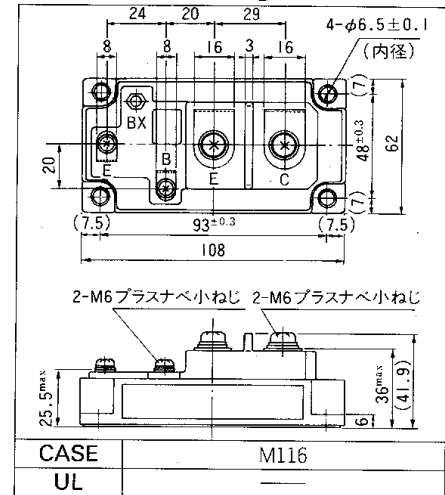
● Electrical Characteristics ($T_c=25^\circ\text{C}$)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I_{CES}	$V_{GE}=0V\ V_{CE}=1200V\ T_c=25^\circ\text{C}$			4.0	mA
		$V_{GE}=0V\ V_{CE}=1200V\ T_c=125^\circ\text{C}$			-	mA
Gate-Emitter Leakage Current	I_{GES}	$V_{CE}=0V\ V_{GE}=\pm 20V$			400	nA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE}=20V\ I_C=200\text{mA}$	3.0		6.0	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V\ I_C=200A$		2.7	3.5	V
Input Capacitance	C_{ies}	$V_{GE}=0V$		36000		pF
Output Capacitance	C_{oes}	$V_{CE}=10V$		-		
Reverse Transfer Capacitance	C_{res}	$f=1\text{MHz}$		-		
Turn-on Time	t_{on}	$V_{CC}=600V$		0.6	0.8	μs
	t_r	$I_C=200A$		0.4	0.6	
Turn-off Time	t_{off}	$V_{GE}=\pm 15V$		0.8	1.5	
	t_f	$R_G=4.7\Omega$		0.3	0.5	
Diode Forward On-Voltage	V_F	$I_F=200A\ V_{GE}=0V$			2.5	V
Reverse Recovery Time	t_{rr}	$I_F=200A\ -di/dt=600A/\mu\text{s}\ V_{GE}=-10V$		200	350	ns

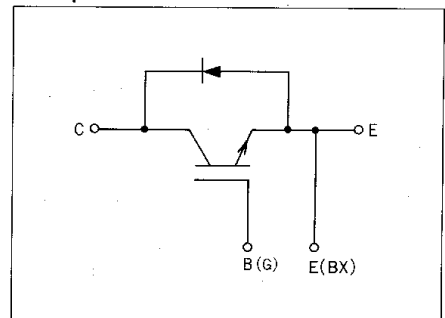
● Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	$R_{th(j-c)}$	IGBT			0.078	°C/W
	$R_{th(j-e)}$	Diode			0.15	
	$R_{th(c-f)}$	With Thermal compound		0.0125		

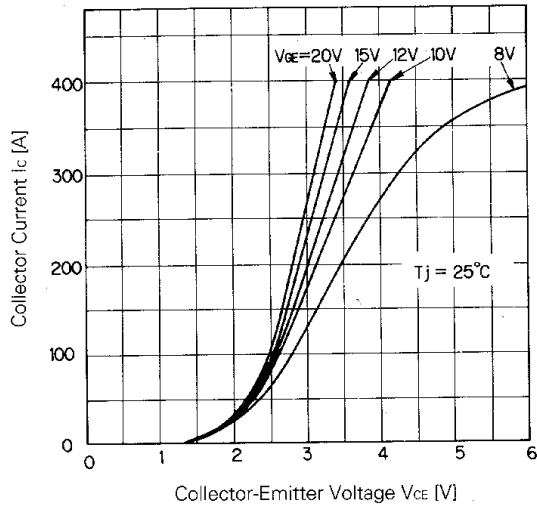
■ Outline Drawings



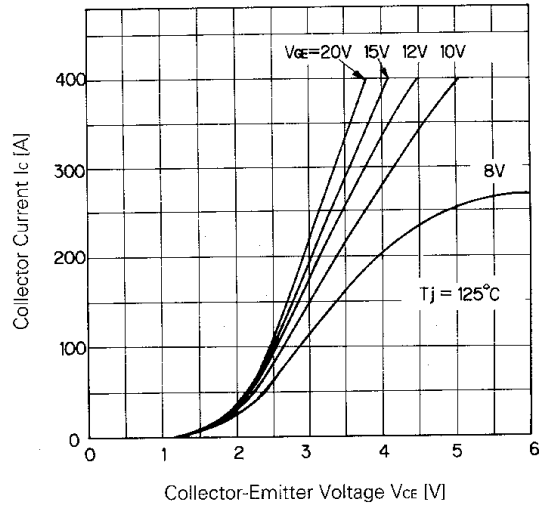
■ Equivelent Circuit Schematic



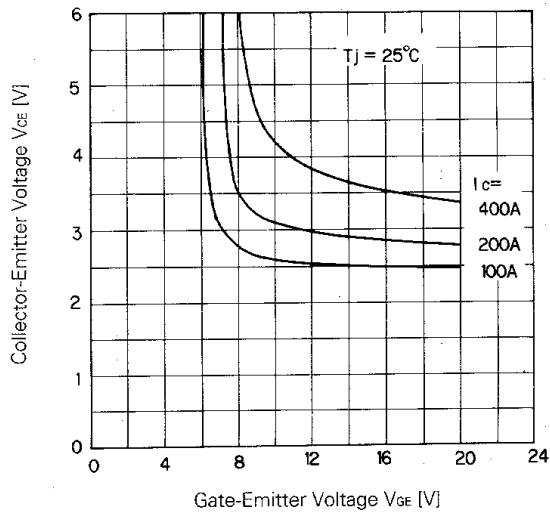
- *1 Recommendable Value 25 to 35kg•cm (M5)
- *2 Recommendable Value 35 to 45kg•cm (M6)
- *3 Recommendable Value 13 to 17kg•cm (M4)



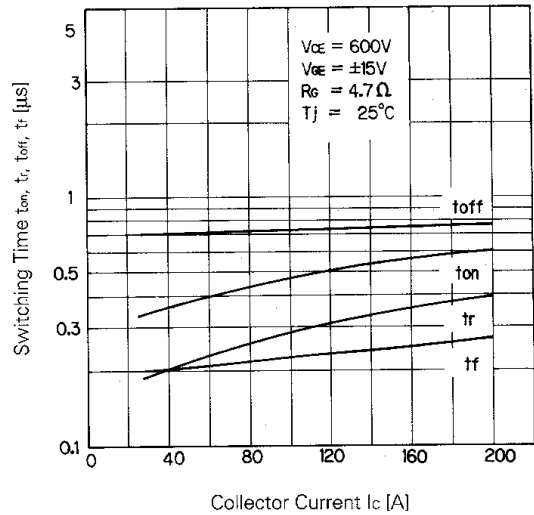
Collector Current vs. Collector-Emitter Voltage



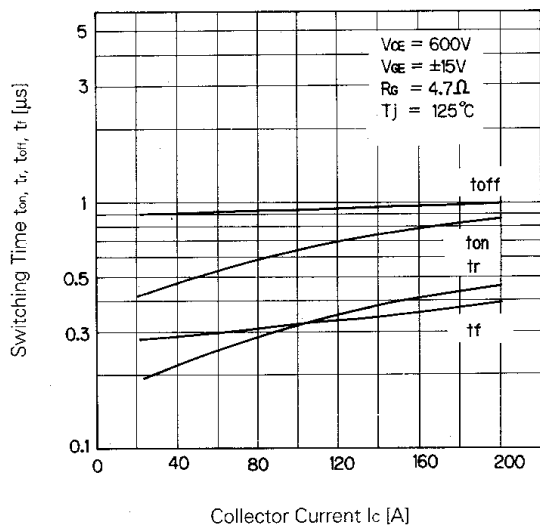
Collector Current vs. Collector-Emitter Voltage



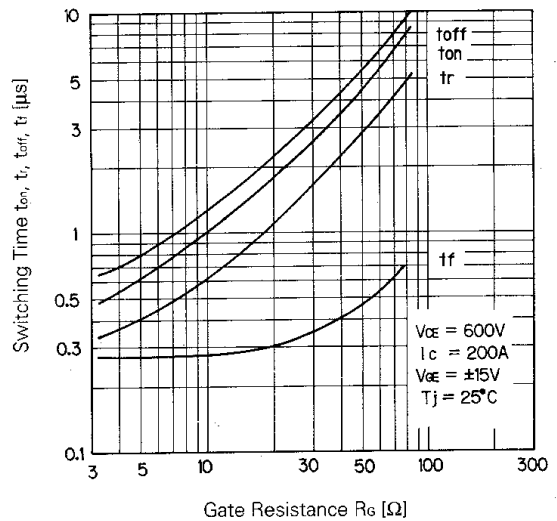
Collector-Emitter Voltage vs. Gate-Emitter Voltage



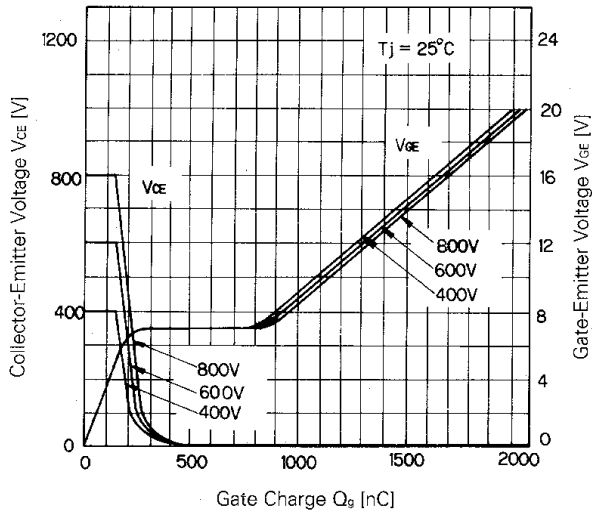
Switching Time



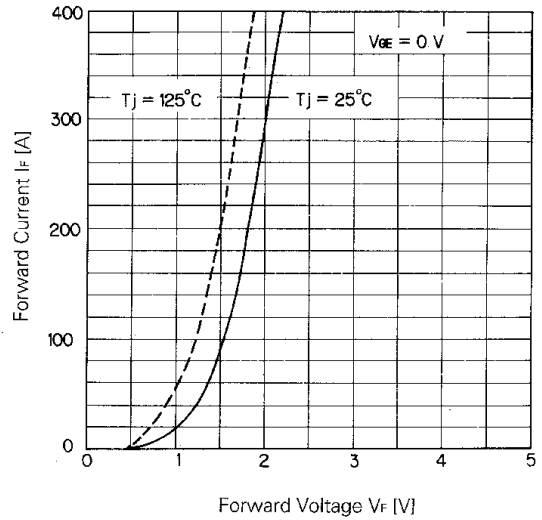
Switching Time



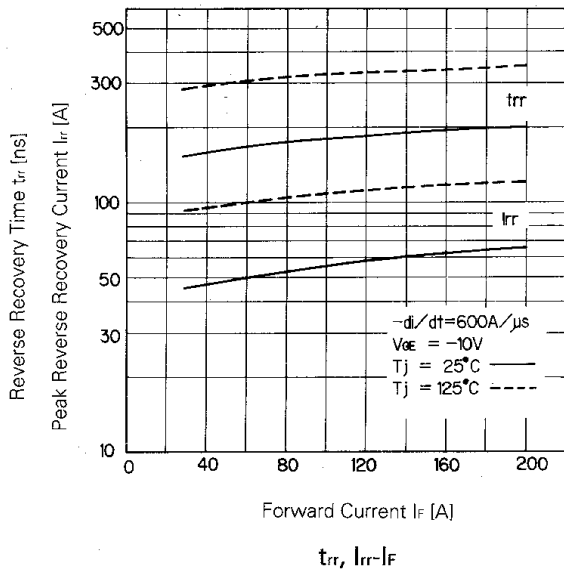
Switching Time-Gate Resistance



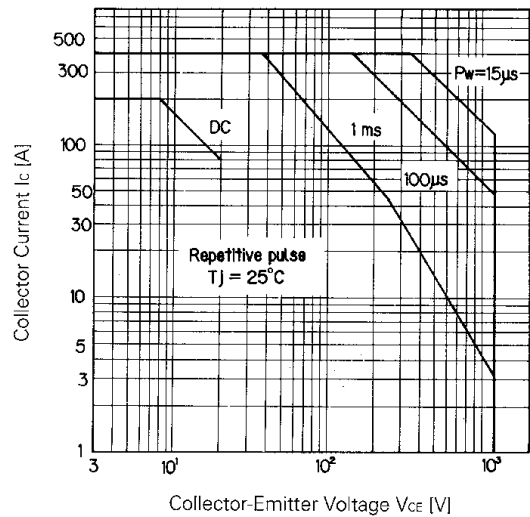
Dynamic Input Characteristic



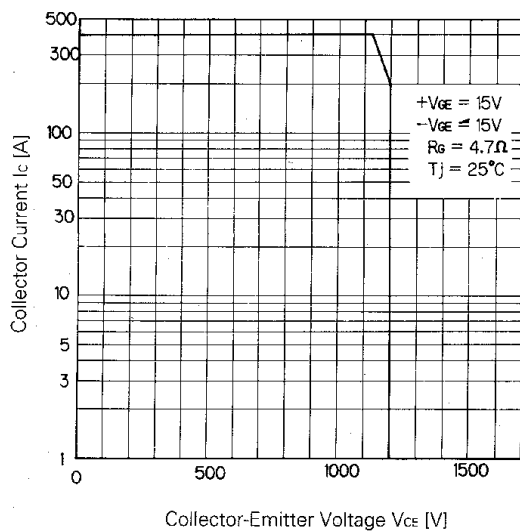
Forward Voltage of Free Wheel Diode



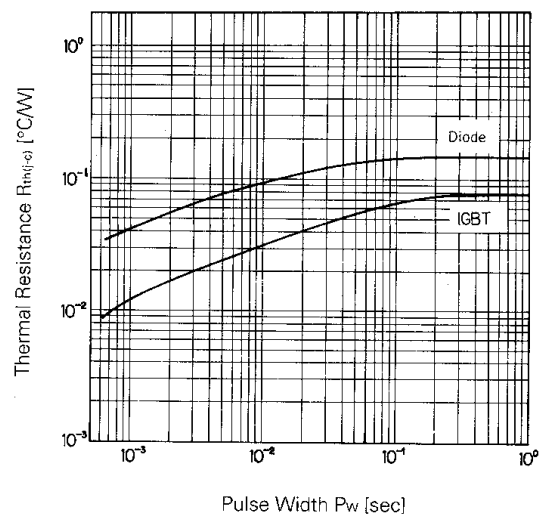
t_{rr} , I_{rr} - I_f



Safe Operating Area



Reverse Biased Safe Operating Area



Transient Thermal Resistance

For more information, contact:

Collmer Semiconductor, Inc.

P.O. Box 702708

Dallas, TX 75370

972-233-1589

972-233-0481 Fax

<http://www.collmer.com>